Vishay Semiconductors

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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 8 A				
V _R	600 V				
V _F at I _F	0.94 V				
t _{rr}	45 ns				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Common cathode				

FEATURES

Ultrafast Rectifier, 2 x 8 A FRED Pt[®]

• Ultrafast recovery time, reduced Q_{rr}, and soft recovery



COMPLIANT HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop, ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V _{RRM}		600	V		
Average rectified forward current	per device		T _{solder pad} = 149 °C	16			
Average rectilied forward current	per diode	IF(AV)		8	٨		
Nen repetitive peak ourse oursent	per device			200	A		
Non-repetitive peak surge current	per diode	IFSM	$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	105			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage, per diode	V _F	I _F = 8 A	-	1.1	1.4	V	
		I _F = 8 A, T _J = 150 °C	-	0.94	1.15		
Povereo lockago ourrent, por diado	I _R	$V_{R} = V_{R}$ rated	-	-	5		
Reverse leakage current, per diode		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	150	μA	
Junction capacitance, per diode	CT	V _R = 600 V	-	8	-	pF	

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V _R = 30 V	-	45	-		
Powerse recovery time	÷	I _F = 0.5 A, I _R = 1 A, I _{rr}	= 0.25 A	-	-	60	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	70	-	ns	
		T _J = 125 °C		-	100	-		
Deels receivers everyont		T _J = 25 °C	$I_F = 8 A$,	-	12	-	^	
Peak recovery current	IRRM	T _J = 125 °C	dI _F /dt = 500 A/µs, V _B = 400 V	-	17	-	A	
	0	T _J = 25 °C		-	430	-		
Reverse recovery charge Q _{rr}		T _J = 125 °C		-	850	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C	
Thermal resistance, per diode junction to mount	R _{thJM}		-	1.8	2.5	°C/W	
Approximate weight				0.55	•	g	
Approximate weight				0.02		oz.	
Marking device		Case style SMPD (TO-263AC)		16CI	DU06		



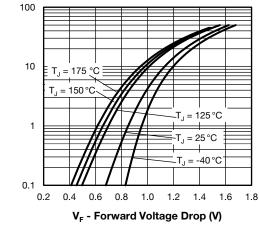


Fig. 1 - Typical Forward Voltage Drop Characteristics

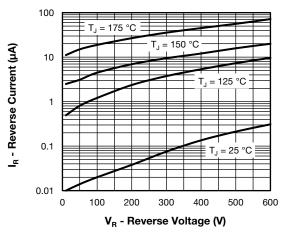


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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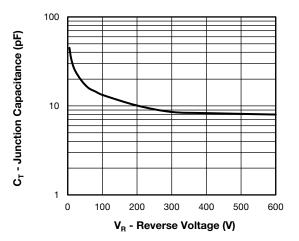


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

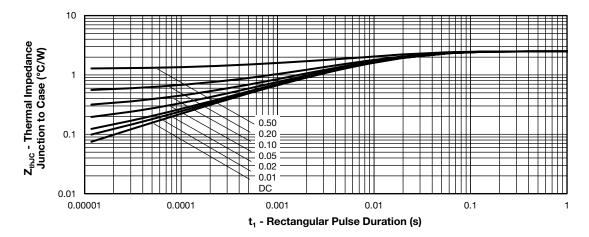
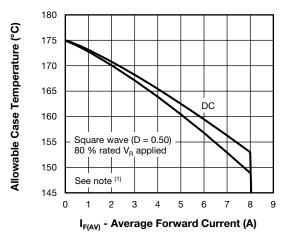
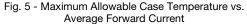


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)



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Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

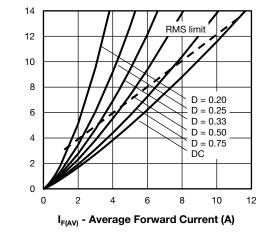


Fig. 6 - Forward Power Loss Characteristics

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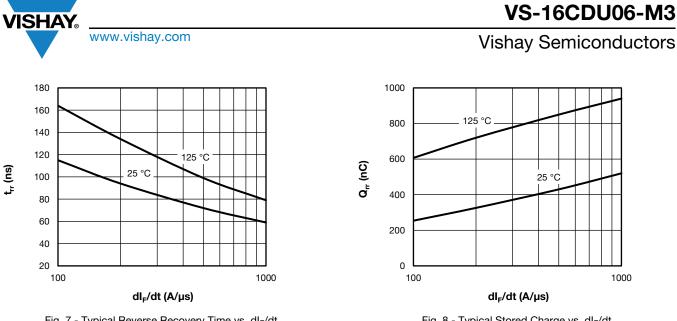


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

Fig. 8 - Typical Stored Charge vs. dl_F/dt

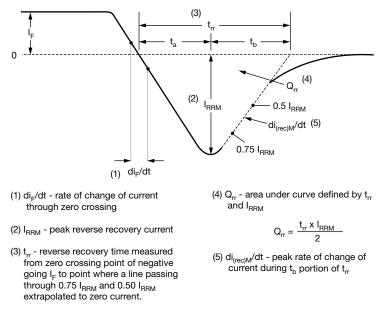


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	16	с	D	U	06	-МЗ
		2	3	4	5	6	7
	1	- Vis	hay Sen	nicondu	ctors pr	oduct	
	2	- Cui	rent rati	ng (16 A	A)		
	3	- Ciro	cuit con	figuratio	n:		
		C =	commo	on catho	de		
	4	- D=	SMPD	packag	е		
	5	- Pro	cess typ	be,			
		U =	ultrafas	st recove	ery		
	6	- Vol	tage coo	de (06 =	600 V)		
	7	M3	3 = halog	gen-free	e, RoHS	-compli	iant, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	RED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-16CDU06-M3/I	2000	2000	13" diameter plastic tape and reel					

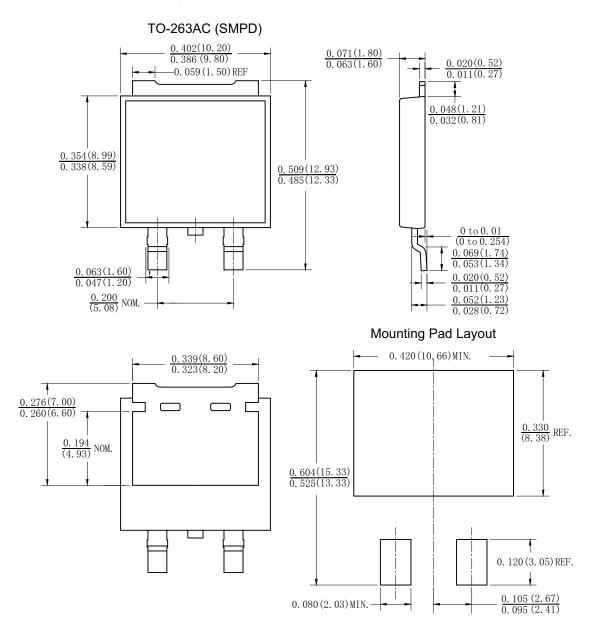
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96575				





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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